

EuGa₂Sb₂: a new Zintl phase with four-bonded gallium and three-bonded antimony in a complex three-dimensional [Ga₂Sb₂] polyanion

Inga Schellenberg · Matthias Eul · Rainer Pöttgen

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Abstract The Zintl phase EuGa₂Sb₂ was synthesized by induction melting of the elements in a sealed tantalum tube. The structure was refined from X-ray single-crystal diffractometer data: new type, *Pnma*, $a = 1834.7(3)$, $b = 432.25(7)$, $c = 674.8(1)$ pm, $wR2 = 0.0377$, $875 F^2$, and 32 variables. The structure consists of a three-dimensional polyanionic [Ga₂Sb₂]²⁻ network with Ga₂⁴⁺ dumb-bells (252.1(1) pm Ga1–Ga2) and antimonide anions, leading to the electron-precise description Eu²⁺[Ga₂Sb₂]²⁻. The divalent character of europium was evident from magnetic susceptibility data and ¹⁵¹Eu Mössbauer spectra. The crystal chemical relationship with the structures of EuGa₂As₂ and BaGa₂Sb₂ is discussed.

Keywords Zintl phase · Europium · Crystal chemistry

Introduction

A large number of intermetallic *RT₂Pn₂* compounds (*R* = rare earth or alkaline earth metal, *T* = transition metal, *Pn* = pnictogen) [1] with tetragonal ThCr₂Si₂ and hexagonal CaAl₂Si₂ type structure has been studied in the last 40 years because of their interesting magnetic and electrical properties. Prominent examples are the mixed-

valence compound EuNi₂P₂ [2, 3], superconducting LaRu₂P₂ [4], and the spin-density system BaFe₂As₂ [5], which becomes superconducting upon partial Ba/K substitution [6]. Chemical bonding in metallic *RT₂Pn₂* compounds can often not be described with simple electron counting rules.

With the alkaline earth elements and divalent europium and ytterbium, many 1:2:2 phosphides, arsenides, and antimonides have been reported which fulfil the Zintl concept [7–9]. Typical examples are the electron-precise Ca Al₂Si₂-type antimonides EuMn₂Sb₂, EuZn₂Sb₂, YbMn₂Sb₂, and YbZn₂Sb₂ with divalent cations and antimonide anions [10]. If one substitutes the divalent transition metal by a trivalent main group cation, such electron-precise 1:2:2 pnictides can only be realized if the triel elements form single bonds, leading to different crystal structures. Recent examples are the phosphides *RIn₂P₂* (*R* = Ca, Sr, Ba, Eu) [11, 12], *RGa₂P₂* (*R* = Ca, Ba, Eu) [13–15], the antimonide BaGa₂Sb₂ [16], the arsenides *RGa₂As₂* (*R* = Ca, Sr, Eu) [13, 15], and EuIn₂As₂ [17]. These pnictides crystallize with different crystal structures with two or three-dimensional [Ga₂*Pn₂*]²⁻ and [In₂*Pn₂*]²⁻ polyanions which are separated and charge-balanced by the divalent cations. The various Ga–Ga (240–251 pm) and In–In (274–277 pm) distances are compatible with single bonds. The dimensionality and distortion of the polyanions is a consequence of the slightly differing size of Ca²⁺, Sr²⁺, Ba²⁺, and Eu²⁺.

In the course of our systematic investigations of CaAl₂Si₂-type europium compounds [10, 18, 19] and other Eu*T₂X₂* intermetallics (*T* = transition metal, *X* = element of the 3rd, 4th, or 5th main group) [20–22] we have now obtained EuGa₂Sb₂, the missing compound in the *RGa₂Sb₂* series with divalent cations. The structure, crystal chemistry, and properties of this antimonide are reported herein.

I. Schellenberg · M. Eul · R. Pöttgen (✉)
Institut für Anorganische und Analytische Chemie,
Westfälische Wilhelms-Universität Münster, Corrensstrasse 30,
48149 Münster, Germany
e-mail: pottgen@uni-muenster.de

Results and discussion

Structure refinement

Careful analysis of the diffractometer data set revealed a primitive orthorhombic lattice, and the systematic extinctions were compatible with space group *Pnma*. The starting atomic positions were obtained from direct methods with Shelxs-97 [23] and the structure was refined using Shelxl-97 [24] (full-matrix least-squares on F^2) with anisotropic atomic displacement parameters for all sites. The occupancy parameters were refined in a separate series of least-squares cycles. All sites were fully occupied within two standard deviations and in the final cycles the ideal values were assumed again. The refinement then smoothly converged to the values listed in Table 1. The final difference Fourier syntheses revealed no significant residues. The refined atomic positions, anisotropic displacement parameters, and interatomic distances are given in Tables 2 and 3.

Crystal chemistry

The antimonide EuGa_2Sb_2 crystallizes with a new structure type. It is the missing compound in the RGa_2Sb_2 series with

Table 1 Crystallographic data and structure refinement for EuGa_2Sb_2 , space group *Pnma*, $Z = 4$

Formula	EuGa_2Sb_2
Molar mass/g mol ⁻¹	534.90
Lattice parameters/pm (Guinier data)	$a = 1834.7(3)$ $b = 432.25(7)$ $c = 674.8(1)$
Cell volume/nm ³	$V = 0.5351$
Density calc./g cm ⁻³	6.64
Crystal size/ μm	$15 \times 20 \times 20$
$h k l$ range	$\pm 25; \pm 6; \pm 9$
$\theta_{\text{min}}/\theta_{\text{max}}/^\circ$	2.2/30.0
Linear absorption coeff./mm ⁻¹	31.3
Max./min. transmission	0.272/0.240
No. of reflections	5829
R_{int}	0.1172
No. of independent reflections	875
Reflections used [$I \geq 2\sigma(I)$]	704
$F(000)$, e	908
R factors $R1/wR2$	0.0263/0.0349
$R1/wR2$ all data	0.0413/0.0377
No. of refined parameters	32
Goodness-of-fit	1.04
Extinction coefficient	0.00138(7)
Diff. Fourier residues/e \AA^{-3}	-2.27, +1.67

Table 2 Atom positions and anisotropic displacement parameters (pm^2) for EuGa_2Sb_2

Atom	x	z	U_{11}	U_{22}	U_{33}	U_{13}	U_{eq}
Eu	0.38486(2)	0.28122(5)	128(2)	118(2)	141(2)	4(1)	129(1)
Ga1	0.20790(5)	0.4632(1)	119(4)	124(4)	141(4)	16(3)	128(2)
Ga2	0.57075(5)	0.0593(1)	146(4)	121(4)	163(4)	24(3)	143(2)
Sb1	0.21296(3)	0.06421(7)	129(2)	102(2)	107(2)	-9(2)	112(1)
Sb2	0.46941(3)	0.73199(7)	138(2)	110(2)	135(2)	-23(2)	128(1)

All atoms lie on Wyckoff positions $4c$ (x $1/4$ z). Coefficients U_{ij} of the anisotropic displacement factor tensor of the atoms are defined by: $-2\pi^2[(ha^*)^2U_{11} + \dots + 2hka^*b^*U_{12}]$. $U_{12} = U_{23} = 0$

Table 3 Interatomic distances (pm) for EuGa_2Sb_2

Eu:	2	Ga2	325.8(1)	Ga2:	1	Ga1	252.1(1)
	2	Sb1	339.7(1)		2	Sb2	268.3(1)
	1	Sb2	341.5(1)		1	Sb2	288.7(1)
	2	Sb2	343.9(1)		2	Eu	325.8(1)
	1	Ga1	347.1(1)		2	Ga2	347.2(1)
	1	Sb1	347.7(1)	Sb1:	2	Ga1	269.1(1)
	2	Ga1	348.9(1)		1	Ga1	269.4(1)
Ga1:	1	Ga2	252.1(1)		2	Eu	339.7(1)
	2	Sb1	269.1(1)		1	Eu	347.7(1)
	1	Sb1	269.4(1)	Sb2:	2	Ga2	268.3(1)
	1	Eu	347.1(1)		1	Ga2	288.7(1)
	2	Eu	348.9(1)		1	Eu	341.5(1)
					2	Eu	343.9(1)

All distances of the first coordination spheres are listed

divalent cations. A view of the EuGa_2Sb_2 structure along the short unit cell axis is presented in Fig. 1. The gallium and antimony atoms build up a three-dimensional $[\text{Ga}_2\text{Sb}_2]$ network which leaves larger cages for the europium atoms. Within the network we observe Ga1–Ga2 distances of 252.1(1) pm, slightly longer than in the Ga_2 dumb-bell (244 pm) of the structure of elemental gallium [25], indicating single-bond character. Both crystallographically independent gallium atoms have three antimony neighbors, leading to a distorted tetrahedral coordination (Fig. 2). The various Ga–Sb distances range from 268.3(1) to 288.7(1) pm, close to the sum of the covalent radii [26] of 266 pm, again signalling single bond character.

Considering these two-centre-two-electron bonds and the divalent character (vide infra) of the europium atoms, we end up with an electron precise Zintl formulation $\text{Eu}^{2+}[\text{Ga}_2]^{4+}[\text{Sb}_2]^{6-}$, or, emphasizing the covalent bond between the gallium dimer and the antimonide entities, $\text{Eu}^{2+}[\text{Ga}_2\text{Sb}_2]^{2-}$. The antimony atoms as the most electronegative component in our compound all point toward the europium atoms which fill pairwise cages of coordination number 11 (5 Ga + 6 Sb). Within the $[\text{Ga}_2\text{Sb}_2]$ network the antimony atoms are well separated.

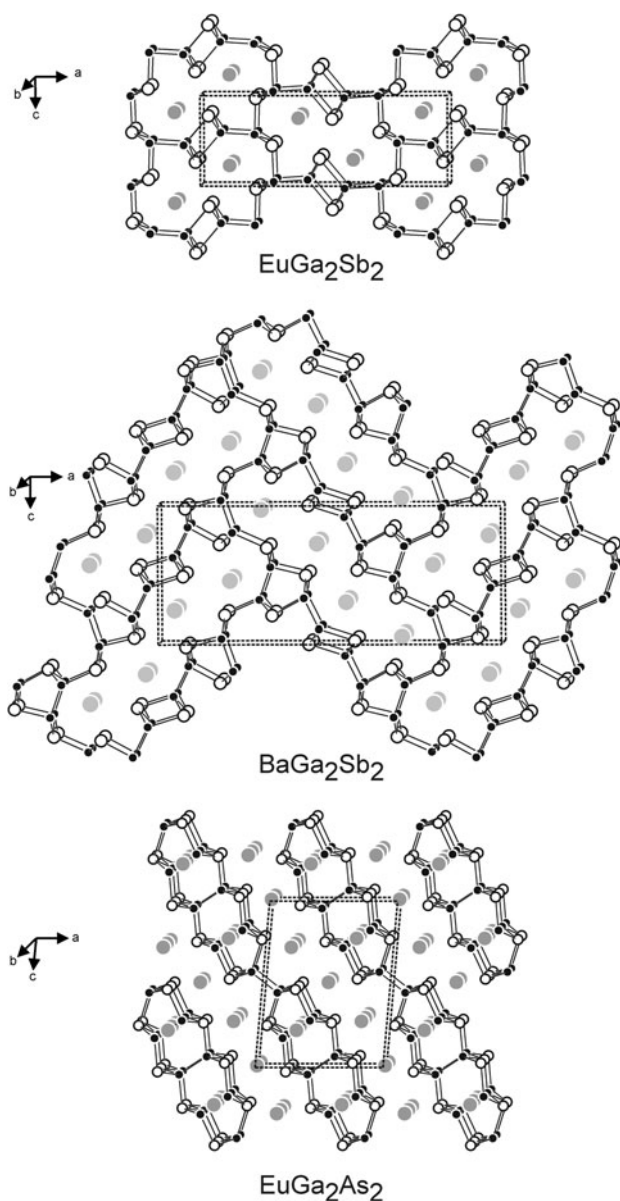


Fig. 1 View of the EuGa₂Sb₂, BaGa₂Sb₂, and EuGa₂As₂ structures along the short unit cell axes. Europium (barium), gallium, and antimony (arsenic) atoms are drawn as medium gray, black filled, and open circles, respectively. The [Ga₂Sb₂] and [Ga₂As₂] polyanions are emphasized

The shortest Sb–Sb distance of 396.7(9) pm cannot be regarded as bonding. Also the europium atoms are well separated. The shortest Eu–Eu distance of 432.25(7) pm corresponds to the *b* lattice parameter.

In Fig. 1 we compare the [Ga₂Sb₂] network of EuGa₂Sb₂ with that in BaGa₂Sb₂ [16] and with the [Ga₂As₂] network in EuGa₂As₂ [13]. The three pnictides are isoelectronic with Ga₂ dumb-bells and Pn^{3−} ions, but their structures are significantly different. With the slightly larger barium atoms one observes larger cavities with four rows of barium cations in one channel compared with two

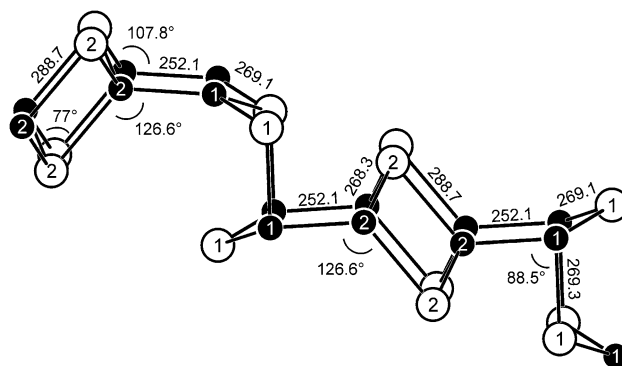


Fig. 2 Cutout of the three-dimensional [Ga₂Sb₂]^{2−} polyanion of EuGa₂Sb₂. Gallium and antimony atoms are drawn as black filled circles and open circles, respectively. Relevant interatomic distances (pm) and bond angles (°) are indicated

rows in the europium compound. In going from EuGa₂Sb₂ to EuGa₂As₂ [13], one reduces the size of the pnictide component, and the resulting [Ga₂As₂] network is now two-dimensional. It is interesting to note that all phosphides and arsenides in these 1:2:2 series have pronounced two-dimensional [Ga₂Pn₂] and [In₂Pn₂] networks, whereas the two antimonides BaGa₂Sb₂ [16] and EuGa₂Sb₂ have three-dimensional networks.

Magnetic properties

The top panel of Fig. 3 shows the magnetic and inverse magnetic susceptibility (χ and χ^{-1} data) of EuGa₂Sb₂ measured at 10 kOe. EuGa₂Sb₂ shows Curie–Weiss behaviour above 50 K with an effective magnetic moment $\mu_{\text{eff}} = 7.47(1) \mu_{\text{B}}/\text{Eu}$ atom and a Weiss temperature $\theta_{\text{p}} = 5.5(3)$ K obtained from a fit of $\chi(T) = C/(T - \theta_{\text{p}})$ in the temperature range of 50–300 K. The effective magnetic moment is somewhat lower than the theoretical value of 7.94 μ_{B} for a free Eu²⁺ ion, which can be attributed to the presence of GaSb as an identifiable impurity seen in the XRD powder pattern. The positive Weiss temperature is indicative of weak ferromagnetic interactions in the paramagnetic region. The onset of magnetic ordering is visible at around 7 K. To determine the exact ordering temperature, low-field (100 Oe) measurements in the zero-field cooled (ZFC) and field-cooled (FC) mode were performed, as seen in the inset. Here, the antiferromagnetic ordering is clearly evident and the Néel temperature was determined to $T_{\text{N}} = 7.8(5)$ K. There is an upturn in the magnetic susceptibility below 5 K which can most likely be attributed to a spin-reorientation. A minor anomaly is also visible at 6.1(5) K, which coincides with the antiferromagnetic ordering temperature of Eu₇Ga₈Sb₈ [27], although this compound could not be detected in the XRD powder pattern.

In the bottom panel of Fig. 3 the magnetization isotherms of EuGa₂Sb₂ measured at 5, 15, and 50 K are

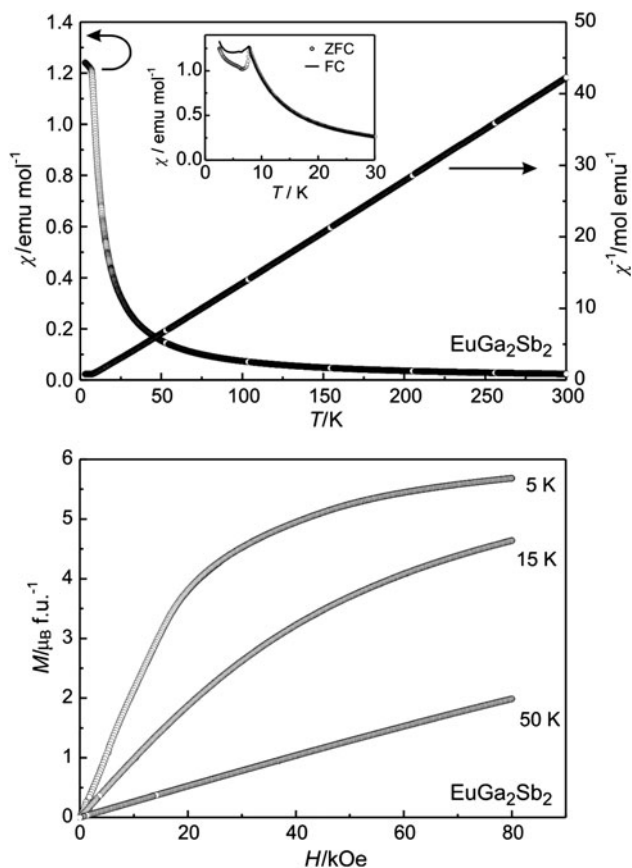


Fig. 3 Top panel magnetic and inverse magnetic susceptibility (χ and χ^{-1} data) of EuGa_2Sb_2 measured at 10 kOe. Inset shows χ data in the low-temperature region measured at 100 Oe in the zero-field-cooled and field-cooled modes. Bottom panel magnetization isotherms of EuGa_2Sb_2 measured at 5, 15, and 50 K

displayed. At 50 K the magnetization increases linearly with increasing field strength as is expected for a paramagnetic material. At 15 K slight curvature of the magnetization is evident, because of saturation effects at low temperatures and high fields. Below T_N (5 K) the magnetization increases nearly linearly up to approximately 18 kOe and then tends towards saturation. The saturation magnetization of $\mu_{\text{sm}} = 5.69(3) \mu_{\text{B}}/\text{Eu}$ atom at 5 K and 80 kOe is slightly lower than the theoretical value of $7 \mu_{\text{B}}$ for Eu^{2+} . Higher external fields are needed to induce full parallel spin alignment.

Mössbauer spectroscopy

The Mössbauer spectra of the new antimonide EuGa_2Sb_2 taken at 77 and 4.2 K are presented in Fig. 4 together with transmission integral fits. The corresponding fitting parameters are listed in Table 4.

The europium spectra are composed of one major resonance at isomer shift values corresponding to divalent europium. The minor component ($\sim 5\%$ intensity) in the

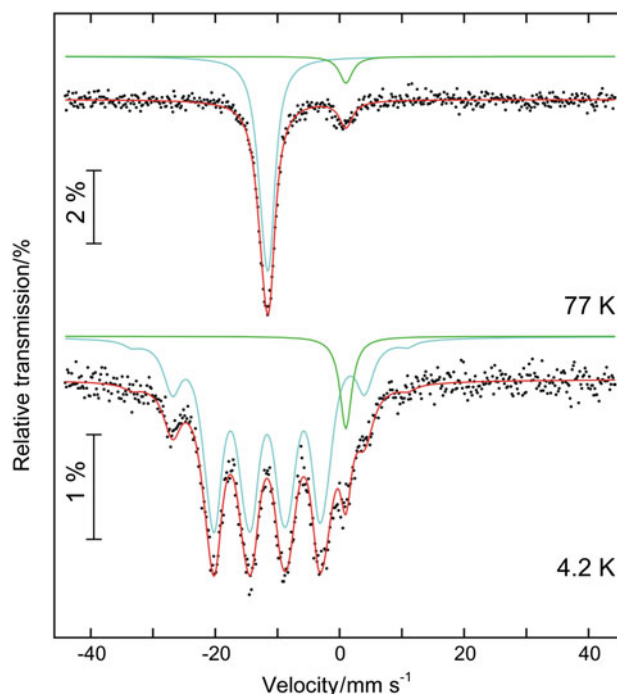


Fig. 4 Experimental and simulated ^{151}Eu Mössbauer spectra of EuGa_2Sb_2 at 77 and 4.2 K

Table 4 Fitting parameters of ^{151}Eu Mössbauer spectroscopic measurements of EuGa_2Sb_2

T/K	$\delta/\text{mm s}^{-1}$	$\Gamma/\text{mm s}^{-1}$	$\Delta E_{\text{Q}}/\text{mm s}^{-1}$	B_{h}/T
77	-11.72(2)	2.37(7)	3.0(2)	–
4.2	-11.62(2)	2.88(5)	-0.47(5)	21.42(5)

Numbers in parentheses represent the statistical errors in the last digit δ isomer shift, Γ experimental line width, ΔE_{Q} electric quadrupole splitting, B_{h} magnetic hyperfine field

range of zero velocity is attributed to an Eu^{3+} impurity, formed by surface oxidation. This Eu^{3+} signal is included as a broad Lorentzian line in the fit at both temperatures. The quadrupole interaction decreases from $3.0(2) \text{ mm s}^{-1}$ at 77 K to $-0.47(5) \text{ mm s}^{-1}$ at 4.2 K. At 4.2 K the europium magnetic moments are in an ordered state leading to a magnetic hyperfine field of 21.42(5) T acting on the nuclear spin levels, resulting in clearly visible Zeeman splittings.

Experimental

Synthesis

Starting materials for the preparation of EuGa_2Sb_2 were sublimed ingots of europium (Smart Elements, $>99.9\%$), gallium lumps (Johnson Matthey, $>99.9\%$), and antimony

shots (ABCR, 99.99%). The air and moisture-sensitive europium ingots were kept under argon before the reaction. The argon was purified before use with titanium sponge (870 K), silica gel, and molecular sieves. The elements were weighed in the ideal 1:2:2 atomic ratio and sealed in a tantalum tube under an argon pressure of 800 mbar in an arc melting apparatus [28]. The tantalum tube was subsequently placed in the water-cooled sample chamber of an induction furnace [29] (Hüttinger Elektronik, Freiburg, Germany; type TIG 2.5/300), heated to ca. 1,680 K, and kept at that temperature for 10 min. Finally, the temperature was reduced to 1,180 K, and the sample was annealed at that temperature for another 3 h and then cooled within the furnace after the power was switched off. The temperature was monitored by use of a Sensor Therm Methis MS09 pyrometer with an accuracy of ± 30 K. No reaction with the container material was observed. The polycrystalline sample is light grey and stable in air for weeks. Small single crystals have a metallic lustre. By-products (which remained after several variations of the synthetic procedure) were GaSb and a trace of EuGa₂.

Scanning electron microscopy

Semiquantitative EDX analyses of the single crystal investigated on the diffractometer and the bulk sample were carried out with a Zeiss EVO MA10 scanning electron microscope with EuF₃, GaP, and Sb as standards. The experimentally observed compositions were close to the ideal composition. No impurity elements were observed.

X-ray diffraction data

The sample was characterized by X-ray powder diffraction using a Guinier camera equipped with an image plate system (Fujifilm, BAS-1800) using Cu K α ₁ radiation and α -quartz ($a = 491.30$, $c = 540.46$ pm) as an internal standard. The orthorhombic lattice parameters were deduced by least-squares refinement of the powder data. To ensure correct indexing, the experimental pattern was compared with a calculated pattern [30] using the positional parameters obtained from the structure refinement.

Irregularly shaped single crystals were obtained from the annealed sample by mechanical fragmentation. The crystals were glued to quartz fibres by use of beeswax and were characterized by Laue photographs on a Buerger camera (white molybdenum radiation, image plate technique, Fujifilm, BAS-1800) in order to check their suitability for intensity data collection. The data set was collected at room temperature by use of a four-circle diffractometer (CAD4) with graphite-monochromated Mo K α radiation and a scintillation counter with pulse height discrimination. The scans were taken in the $\omega/2\theta$ mode and an empirical

absorption correction was applied on the basis of psi-scan data, accompanied by a spherical absorption correction. All relevant crystallographic data and details of the data collection and evaluation are listed in Table 1. Further information on the structure refinement is available from Fachinformationszentrum Karlsruhe, 76344 Eggenstein-Leopoldshafen (Germany), by quoting the registry no. CSD-423030.

Magnetic measurements

For magnetic measurements 9.760 mg of the polycrystalline sample of EuGa₂Sb₂ were packed in Kapton foil and attached to a sample holder rod. The measurements were performed using the VSM option of a Quantum Design physical property measurement system (PPMS), in the temperature range 2.5–300 K and with magnetic flux densities up to 80 kOe.

Mössbauer spectroscopy

The 21.53 keV transition of ¹⁵¹Eu with an activity of 130 MBq (2% of the total activity of a ¹⁵¹Sm:EuF₃ source) was used for the Mössbauer spectroscopic experiments, which were conducted in the usual transmission geometry. The measurements were performed with a commercial helium-bath cryostat. The temperature of the absorber was varied between 4.2 K and room temperature, and the source was kept at room temperature. The temperature was monitored by use of a resistance thermometer (± 0.5 K accuracy). The sample was enclosed in a small PVC container at a thickness corresponding to approximately 10 mg Mössbauer active element/cm².

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